

HMC358MS8GE

Data Sheet

MMIC VCO w/ BUFFER AMPLIFIER, 5.8

Manufacturers <u>Analog Devices, Inc</u>

Package/Case MSOP-8

Product Type RF Integrated Circuits

RoHS Pb-free Halide free



Images are for reference only

Please submit RFQ for HMC358MS8GE or Email to us: sales@ovaga.com We will contact you in 12 hours.

RFO

General Description

The HMC358MS8G(E) is a GaAs InGaP Heterojunction Bipolar Transistor (HBT) MMIC VCO. The HMC358MS8G(E) integrates resonators, negative resistance devices, varactor diodes, and buffer amplifiers. The VCO's phase noise performance is excellent over temperature, shock, and process due to the oscillator's monolithic structure. Power output is 11 dBm typical from a 3V supply voltage. The voltage controlled oscillator is packaged in a low cost, surface mount 8 lead MSOP package with an exposed base for improved RF and thermal performance.

Applications

Lifecycle

UNII & Point-to-Point Radios

802.11a & HiperLAN WLAN

VSAT Radios

Features Application

Pout: +11 dBm UNII & Point-to-Point Radios

Phase Noise: -110 dBc/Hz @100 KHz 802.11a & HiperLAN WLAN

No External Resonator Needed VSAT Radios

Single Supply: 3V @ 100 mA

15 mm² MSOP8G SMT Package



Related Products



HMC3653LP3BE
Analog Devices, Inc
QFN-12



HMC253AQS24
Analog Devices, Inc
24-SSOP (0.154, 3.90mm Width)



HMC441LP3E
Analog Devices, Inc
QFN-16



HMC948LP3E
Analog Devices, Inc
LP3



<u>HMC490</u>

Analog Devices, Inc SMD



HMC453ST89E
Analog Devices, Inc
ST89E



HMC618ALP3E

Analog Devices, Inc QFN-16



HMC463LP5E

Analog Devices, Inc QFN-32